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What is "Embedded - Microcontrollers"?

"Embedded - Microcontrollers" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

Applications of "<u>Embedded - Microcontrollers</u>"

Details	
Product Status	Not For New Designs
Core Processor	ARM® Cortex®-M3
Core Size	32-Bit Single-Core
Speed	32MHz
Connectivity	EBI/EMI, I ² C, IrDA, SmartCard, SPI, UART/USART
Peripherals	Brown-out Detect/Reset, DMA, POR, PWM, WDT
Number of I/O	17
Program Memory Size	8KB (8K x 8)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	2K x 8
Voltage - Supply (Vcc/Vdd)	1.85V ~ 3.8V
Data Converters	-
Oscillator Type	Internal
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	24-VQFN Exposed Pad
Supplier Device Package	24-QFN (5x5)
Purchase URL	https://www.e-xfl.com/product-detail/silicon-labs/efm32tg108f8-qfn24



1 Ordering Information

Table 1.1 (p. 2) shows the available EFM32TG108 devices.

Table 1.1. Ordering Information

Ordering Code	Flash (kB)	RAM (kB)	Max Speed (MHz)	Supply Voltage (V)	Temperature (°C)	Package
EFM32TG108F4-QFN24	4	2	32	1.98 - 3.8	-40 - 85	QFN24
EFM32TG108F8-QFN24	8	2	32	1.98 - 3.8	-40 - 85	QFN24
EFM32TG108F16-QFN24	16	4	32	1.98 - 3.8	-40 - 85	QFN24
EFM32TG108F32-QFN24	32	4	32	1.98 - 3.8	-40 - 85	QFN24

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divided into two blocks; the main block and the information block. Program code is normally written to the main block. Additionally, the information block is available for special user data and flash lock bits. There is also a read-only page in the information block containing system and device calibration data. Read and write operations are supported in the energy modes EM0 and EM1.

2.1.4 Direct Memory Access Controller (DMA)

The Direct Memory Access (DMA) controller performs memory operations independently of the CPU. This has the benefit of reducing the energy consumption and the workload of the CPU, and enables the system to stay in low energy modes when moving for instance data from the USART to RAM or from the External Bus Interface to a PWM-generating timer. The DMA controller uses the PL230 μ DMA controller licensed from ARM.

2.1.5 Reset Management Unit (RMU)

The RMU is responsible for handling the reset functionality of the EFM32TG.

2.1.6 Energy Management Unit (EMU)

The Energy Management Unit (EMU) manage all the low energy modes (EM) in EFM32TG microcontrollers. Each energy mode manages if the CPU and the various peripherals are available. The EMU can also be used to turn off the power to unused SRAM blocks.

2.1.7 Clock Management Unit (CMU)

The Clock Management Unit (CMU) is responsible for controlling the oscillators and clocks on-board the EFM32TG. The CMU provides the capability to turn on and off the clock on an individual basis to all peripheral modules in addition to enable/disable and configure the available oscillators. The high degree of flexibility enables software to minimize energy consumption in any specific application by not wasting power on peripherals and oscillators that are inactive.

2.1.8 Watchdog (WDOG)

The purpose of the watchdog timer is to generate a reset in case of a system failure, to increase application reliability. The failure may e.g. be caused by an external event, such as an ESD pulse, or by a software failure.

2.1.9 Peripheral Reflex System (PRS)

The Peripheral Reflex System (PRS) system is a network which lets the different peripheral module communicate directly with each other without involving the CPU. Peripheral modules which send out Reflex signals are called producers. The PRS routes these reflex signals to consumer peripherals which apply actions depending on the data received. The format for the Reflex signals is not given, but edge triggers and other functionality can be applied by the PRS.

2.1.10 Inter-Integrated Circuit Interface (I2C)

The I^2C module provides an interface between the MCU and a serial I^2C -bus. It is capable of acting as both a master and a slave, and supports multi-master buses. Both standard-mode, fast-mode and fast-mode plus speeds are supported, allowing transmission rates all the way from 10 kbit/s up to 1 Mbit/s. Slave arbitration and timeouts are also provided to allow implementation of an SMBus compliant system. The interface provided to software by the I^2C module, allows both fine-grained control of the transmission process and close to automatic transfers. Automatic recognition of slave addresses is provided in all energy modes.



2.1.11 Universal Synchronous/Asynchronous Receiver/Transmitter (USART)

The Universal Synchronous Asynchronous serial Receiver and Transmitter (USART) is a very flexible serial I/O module. It supports full duplex asynchronous UART communication as well as RS-485, SPI, MicroWire and 3-wire. It can also interface with ISO7816 SmartCards, IrDA and I2S devices.

2.1.12 Pre-Programmed UART Bootloader

The bootloader presented in application note AN0003 is pre-programmed in the device at factory. Auto-baud and destructive write are supported. The autobaud feature, interface and commands are described further in the application note.

2.1.13 Low Energy Universal Asynchronous Receiver/Transmitter (LEUART)

The unique LEUARTTM, the Low Energy UART, is a UART that allows two-way UART communication on a strict power budget. Only a 32.768 kHz clock is needed to allow UART communication up to 9600 baud/s. The LEUART includes all necessary hardware support to make asynchronous serial communication possible with minimum of software intervention and energy consumption.

2.1.14 Timer/Counter (TIMER)

The 16-bit general purpose Timer has 3 compare/capture channels for input capture and compare/Pulse-Width Modulation (PWM) output.

2.1.15 Real Time Counter (RTC)

The Real Time Counter (RTC) contains a 24-bit counter and is clocked either by a 32.768 kHz crystal oscillator, or a 32.768 kHz RC oscillator. In addition to energy modes EM0 and EM1, the RTC is also available in EM2. This makes it ideal for keeping track of time since the RTC is enabled in EM2 where most of the device is powered down.

2.1.16 Low Energy Timer (LETIMER)

The unique LETIMERTM, the Low Energy Timer, is a 16-bit timer that is available in energy mode EM2 in addition to EM1 and EM0. Because of this, it can be used for timing and output generation when most of the device is powered down, allowing simple tasks to be performed while the power consumption of the system is kept at an absolute minimum. The LETIMER can be used to output a variety of waveforms with minimal software intervention. It is also connected to the Real Time Counter (RTC), and can be configured to start counting on compare matches from the RTC.

2.1.17 Pulse Counter (PCNT)

The Pulse Counter (PCNT) can be used for counting pulses on a single input or to decode quadrature encoded inputs. It runs off either the internal LFACLK or the PCNTn_S0IN pin as external clock source. The module may operate in energy mode EM0 - EM3.

2.1.18 Analog Comparator (ACMP)

The Analog Comparator is used to compare the voltage of two analog inputs, with a digital output indicating which input voltage is higher. Inputs can either be one of the selectable internal references or from external pins. Response time and thereby also the current consumption can be configured by altering the current supply to the comparator.

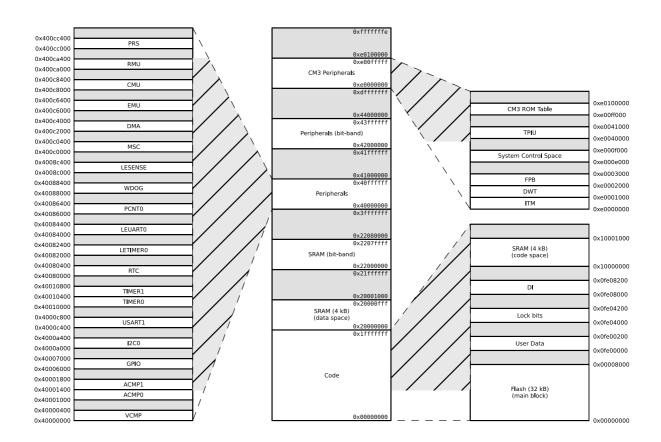


Module	Configuration	Pin Connections
LETIMER0	Full configuration	LET0_O[1:0]
PCNT0	Full configuration, 16-bit count register	PCNT0_S[1:0]
ACMP0	Full configuration	ACMP0_CH[1:0], ACMP0_O
ACMP1	Full configuration	ACMP1_CH[1:0], ACMP1_O
VCMP	Full configuration	NA
GPIO	17 pins	Available pins are shown in Table 4.3 (p. 33)

2.3 Memory Map

The *EFM32TG108* memory map is shown in Figure 2.2 (p. 7), with RAM and Flash sizes for the largest memory configuration.

Figure 2.2. EFM32TG108 Memory Map with largest RAM and Flash sizes





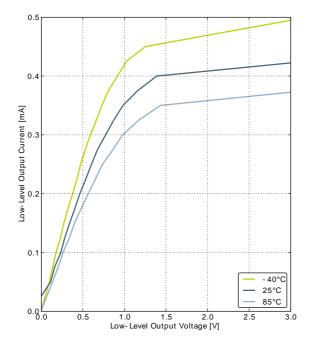
3.4 Current Consumption

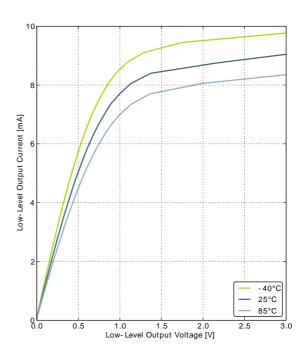
Table 3.3. Current Consumption

Symbol	Parameter	Condition	Min	Тур	Max	Unit
		32 MHz HFXO, all peripheral clocks disabled, V _{DD} = 3.0 V		157		μΑ/ MHz
		28 MHz HFRCO, all peripheral clocks disabled, V _{DD} = 3.0 V		150	170	μΑ/ MHz
I _{EMO}	EM0 current. No prescaling. Running	21 MHz HFRCO, all peripheral clocks disabled, V _{DD} = 3.0 V		153	172	μΑ/ MHz
	prime number cal- culation code from Flash. (Production	14 MHz HFRCO, all peripheral clocks disabled, V _{DD} = 3.0 V		155	175	μΑ/ MHz
	test condition = 14 MHz)	11 MHz HFRCO, all peripheral clocks disabled, V _{DD} = 3.0 V		157	178	μΑ/ MHz
		6.6 MHz HFRCO, all peripheral clocks disabled, V _{DD} = 3.0 V		162	183	μΑ/ MHz
		1.2 MHz HFRCO, all peripheral clocks disabled, V _{DD} = 3.0 V		200	240	μΑ/ MHz
		32 MHz HFXO, all peripheral clocks disabled, V _{DD} = 3.0 V		53		μΑ/ MHz
		28 MHz HFRCO, all peripheral clocks disabled, V _{DD} = 3.0 V		51	57	μΑ/ MHz
		21 MHz HFRCO, all peripheral clocks disabled, V _{DD} = 3.0 V		55	59	μΑ/ MHz
I _{EM1}	EM1 current (Production test condition = 14 MHz)	14 MHz HFRCO, all peripheral clocks disabled, V _{DD} = 3.0 V		56	61	μΑ/ MHz
	,	11 MHz HFRCO, all peripheral clocks disabled, V _{DD} = 3.0 V		58	63	μΑ/ MHz
		6.6 MHz HFRCO, all peripheral clocks disabled, V _{DD} = 3.0 V		63	68	μΑ/ MHz
		1.2 MHz HFRCO. all peripheral clocks disabled, V _{DD} = 3.0 V		100	122	μΑ/ MHz
	FM2 ourrent	EM2 current with RTC prescaled to 1 Hz, 32.768 kHz LFRCO, V _{DD} = 3.0 V, T _{AMB} =25°C		1.0	1.2	μА
EM2	EM2 current	EM2 current with RTC prescaled to 1 Hz, 32.768 kHz LFRCO, V _{DD} = 3.0 V, T _{AMB} =85°C		2.4	5.0	μА
l	EM3 current	V _{DD} = 3.0 V, T _{AMB} =25°C		0.59	1.0	μΑ
'EM3	ENIS CUITETIL	V _{DD} = 3.0 V, T _{AMB} =85°C		2.0	4.5	μΑ
leve	EM4 current	V _{DD} = 3.0 V, T _{AMB} =25°C		0.02	0.055	μΑ
I _{EM2}	LIVIT CUITCIIL	V _{DD} = 3.0 V, T _{AMB} =85°C		0.25	0.70	μΑ



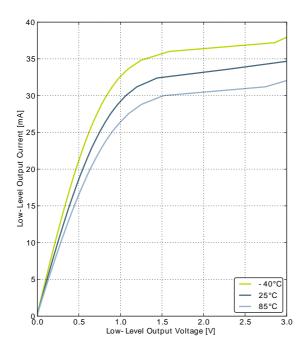
Figure 3.6. Typical Low-Level Output Current, 3V Supply Voltage

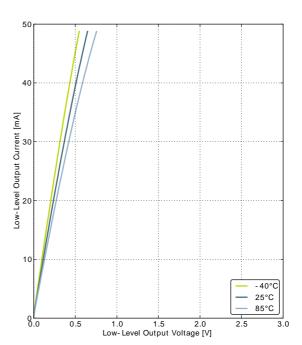




GPIO_Px_CTRL DRIVEMODE = LOWEST





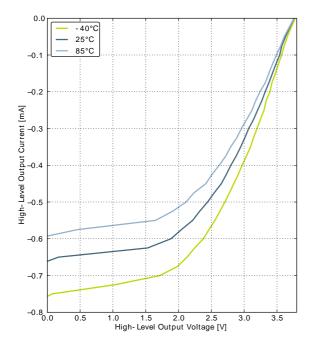


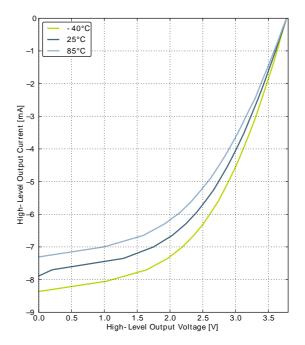
GPIO_Px_CTRL DRIVEMODE = STANDARD

GPIO_Px_CTRL DRIVEMODE = HIGH



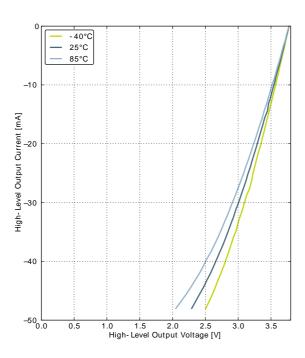
Figure 3.9. Typical High-Level Output Current, 3.8V Supply Voltage

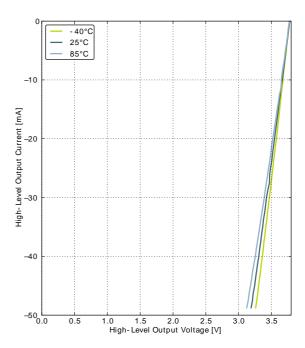




GPIO_Px_CTRL DRIVEMODE = LOWEST





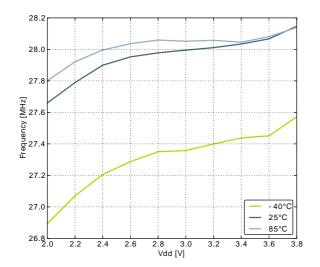


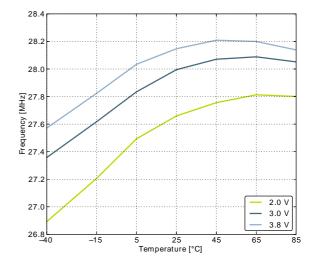
GPIO_Px_CTRL DRIVEMODE = STANDARD

GPIO_Px_CTRL DRIVEMODE = HIGH



Figure 3.16. Calibrated HFRCO 28 MHz Band Frequency vs Supply Voltage and Temperature





3.9.5 AUXHFRCO

Table 3.12. AUXHFRCO

Symbol	Parameter	Condition	Min	Тур	Max	Unit
		28 MHz frequency band	27.16	28.0	28.84	MHz
f _{AUXHFRCO}		21 MHz frequency band	20.37	21.0	21.63	MHz
	Oscillation frequen-	14 MHz frequency band	13.58	14.0	14.42	MHz
	cy, V _{DD} = 3.0 V, T _{AMB} =25°C	11 MHz frequency band	10.67	11.0	11.33	MHz
		7 MHz frequency band	6.40 ¹	6.60 ¹	6.80 ¹	MHz
		1 MHz frequency band	1.16 ²	1.20 ²	28.84 MHz 21.0 21.63 MHz 4.0 14.42 MHz 1.0 11.33 MHz 60 ¹ 6.80 ¹ MHz 20 ² 1.24 ² MHz 0.6 Cyc	MHz
t _{AUXHFRCO_settlin}	Settling time after start-up	f _{AUXHFRCO} = 14 MHz		0.6		Cycles
TUNESTEP _{AUX} HFRCO	Frequency step for LSB change in TUNING value			0.3 ³		%

¹For devices with prod. rev. < 19, Typ = 7MHz and Min/Max values not applicable.

3.9.6 ULFRCO

Table 3.13. ULFRCO

Symbol	Parameter	Condition	Min	Тур	Max	Unit
f _{ULFRCO}	Oscillation frequen- cy	25°C, 3V	0.70		1.75	kHz
TC _{ULFRCO}	Temperature coefficient			0.05		%/°C
VC _{ULFRCO}	Supply voltage co- efficient			-18.2		%/V

²For devices with prod. rev. < 19, Typ = 1MHz and Min/Max values not applicable.

³The TUNING field in the CMU_AUXHFRCOCTRL register may be used to adjust the AUXHFRCO frequency. There is enough adjustment range to ensure that the frequency bands above 7 MHz will always have some overlap across supply voltage and temperature. By using a stable frequency reference such as the LFXO or HFXO, a firmware calibration routine can vary the TUNING bits and the frequency band to maintain the AUXHFRCO frequency at any arbitrary value between 7 MHz and 28 MHz across operating conditions.



3.10 Analog Comparator (ACMP)

Table 3.14. ACMP

Symbol	Parameter	Condition	Min	Тур	Max	Unit
V _{ACMPIN}	Input voltage range		0		V _{DD}	V
V _{ACMPCM}	ACMP Common Mode voltage range		0		V _{DD}	V
		BIASPROG=0b0000, FULL- BIAS=0 and HALFBIAS=1 in ACMPn_CTRL register		0.1	0.6	μΑ
I _{ACMP}	Active current	BIASPROG=0b1111, FULL- BIAS=0 and HALFBIAS=0 in ACMPn_CTRL register		2.87	12	μΑ
		BIASPROG=0b1111, FULL- BIAS=1 and HALFBIAS=0 in ACMPn_CTRL register		195	520	μА
I _{ACMPREF}	Current consump- tion of internal volt- age reference	Internal voltage reference off. Using external voltage reference		0.0	0.5	μА
	age reference	Internal voltage reference		2.15	3.00	μA
V _{ACMPOFFSET}	Offset voltage	BIASPROG= 0b1010, FULL- BIAS=0 and HALFBIAS=0 in ACMPn_CTRL register	-12	0	12	mV
V _{ACMPHYST}	ACMP hysteresis	Programmable		17		mV
		CSRESSEL=0b00 in ACMPn_INPUTSEL		39		kOhm
D	Capacitive Sense	CSRESSEL=0b01 in ACMPn_INPUTSEL		71		kOhm
R _{CSRES}	Internal Resistance	CSRESSEL=0b10 in ACMPn_INPUTSEL		104		kOhm
		CSRESSEL=0b11 in ACMPn_INPUTSEL		136		kOhm
t _{ACMPSTART}	Startup time				10	μs

The total ACMP current is the sum of the contributions from the ACMP and its internal voltage reference as given in Equation 3.1 (p. 25). $I_{ACMPREF}$ is zero if an external voltage reference is used.

Total ACMP Active Current
$$I_{ACMPTOTAL} = I_{ACMP} + I_{ACMPREF}$$
(3.1)



3.11 Voltage Comparator (VCMP)

Table 3.15. VCMP

Symbol	Parameter	Condition	Min	Тур	Max	Unit
V _{VCMPIN}	Input voltage range			V _{DD}		V
V _{VCMPCM}	VCMP Common Mode voltage range			V _{DD}		V
I _{VCMP}	Active current	BIASPROG=0b0000 and HALFBIAS=1 in VCMPn_CTRL register		0.3	0.6	μА
VCMP	Active current	BIASPROG=0b1111 and HALFBIAS=0 in VCMPn_CTRL register. LPREF=0.		22	30	μΑ
t _{VCMPREF}	Startup time reference generator	NORMAL		10		μs
V	Officet voltage	Single ended		10		mV
V _{VCMPOFFSET} O	Offset voltage	Differential		10		mV
V _{VCMPHYST}	VCMP hysteresis			17		mV
t _{VCMPSTART}	Startup time				10	μs

The V_{DD} trigger level can be configured by setting the TRIGLEVEL field of the VCMP_CTRL register in accordance with the following equation:

VCMP Trigger Level as a Function of Level Setting $V_{DD \ Trigger \ Level} = 1.667 V + 0.034 \ \times TRIGLEVEL \tag{3.2}$

3.12 I2C

Table 3.16. I2C Standard-mode (Sm)

Symbol	Parameter	Min	Тур	Max	Unit
f _{SCL}	SCL clock frequency	0		100 ¹	kHz
t _{LOW}	SCL clock low time	4.7			μs
t _{HIGH}	SCL clock high time	4.0			μs
t _{SU,DAT}	SDA set-up time	250			ns
t _{HD,DAT}	SDA hold time	8		3450 ^{2,3}	ns
t _{SU,STA}	Repeated START condition set-up time	4.7			μs
t _{HD,STA}	(Repeated) START condition hold time	4.0			μs
t _{SU,STO}	STOP condition set-up time	4.0			μs
t _{BUF}	Bus free time between a STOP and START condition	4.7			μs

¹For the minimum HFPERCLK frequency required in Standard-mode, see the I2C chapter in the EFM32TG Reference Manual.

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²The maximum SDA hold time (t_{HD,DAT}) needs to be met only when the device does not stretch the low time of SCL (t_{LOW}).

³When transmitting data, this number is guaranteed only when I2Cn_CLKDIV < ((3450*10⁻⁹ [s] * f_{HFPERCLK} [Hz]) - 4).



4 Pinout and Package

Note

Please refer to the application note "AN0002 EFM32 Hardware Design Considerations" for guidelines on designing Printed Circuit Boards (PCB's) for the EFM32TG108.

4.1 Pinout

The *EFM32TG108* pinout is shown in Figure 4.1 (p. 30) and Table 4.1 (p. 30). Alternate locations are denoted by "#" followed by the location number (Multiple locations on the same pin are split with "/"). Alternate locations can be configured in the LOCATION bitfield in the *_ROUTE register in the module in question.

Figure 4.1. EFM32TG108 Pinout (top view, not to scale)

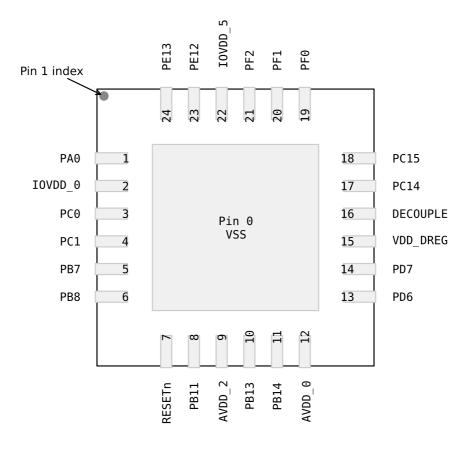


Table 4.1. Device Pinout

	QFN24 Pin# and Name		Pin Alternate Function		
Pin #	Pin Name			Communication	Other
0	VSS	Ground.			
1	PA0		TIM0_CC0 #0/1/4	LEU0_RX #4 I2C0_SDA #0	PRS_CH0 #0 GPIO_EM4WU0



	QFN24 Pin# and Name		Pin Alternate Function	onality / Description	
Pin#	Pin Name	Analog	Timers	Communication	Other
2	IOVDD_0	Digital IO power supply 0.			
3	PC0	ACMP0_CH0	TIM0_CC1 #4 PCNT0_S0IN #2	US1_TX #0 I2C0_SDA #4	LES_CH0 #0 PRS_CH2 #0
4	PC1	ACMP0_CH1	TIM0_CC2 #4 PCNT0_S1IN #2	US1_RX #0 I2C0_SCL #4	LES_CH1 #0 PRS_CH3 #0
5	PB7	LFXTAL_P	TIM1_CC0 #3	US1_CLK #0	
6	PB8	LFXTAL_N	TIM1_CC1 #3	US1_CS #0	
7	RESETn	Reset input, active low. To apply an external reset soul ensure that reset is released.	rce to this pin, it is required to or	nly drive this pin low during reset,	and let the internal pull-up
8	PB11		TIM1_CC2 #3 LETIM0_OUT0 #1		
9	AVDD_2	Analog power supply 2.			
10	PB13	HFXTAL_P		LEU0_TX #1	
11	PB14	HFXTAL_N		LEU0_RX #1	
12	AVDD_0	Analog power supply 0.			
13	PD6		TIM1_CC0 #4 LETIM0_OUT0 #0 PCNT0_S0IN #3	US1_RX #2 I2C0_SDA #1	LES_ALTEX0 #0 ACMP0_O #2
14	PD7		TIM1_CC1 #4 LETIM0_OUT1 #0 PCNT0_S1IN #3	US1_TX #2 I2C0_SCL #1	CMU_CLK0 #2 LES_ALTEX1 #0 ACMP1_O #2
15	VDD_DREG	Power supply for on-chip voltage	ge regulator.		
16	DECOUPLE	Decouple output for on-chip vo	oltage regulator. An external capa	acitance of size C _{DECOUPLE} is req	uired at this pin.
17	PC14	ACMP1_CH6	TIM1_CC1 #0 PCNT0_S1IN #0		LES_CH14 #0
18	PC15	ACMP1_CH7	TIM1_CC2 #0		LES_CH15 #0 DBG_SWO #1
19	PF0		TIM0_CC0 #5 LETIM0_OUT0 #2	US1_CLK #2 LEU0_TX #3 I2C0_SDA #5	DBG_SWCLK #0/1 BOOT_TX
20	PF1		TIM0_CC1 #5 LETIM0_OUT1 #2	US1_CS #2 LEU0_RX #3 I2C0_SCL #5	DBG_SWDIO #0/1 GPIO_EM4WU3 BOOT_RX
21	PF2		TIM0_CC2 #5	LEU0_TX #4	ACMP1_O #0 DBG_SWO #0 GPIO_EM4WU4
22	IOVDD_5	Digital IO power supply 5.			
23	PE12		TIM1_CC2 #1	I2C0_SDA #6	CMU_CLK1 #2 LES_ALTEX6 #0
24	PE13			I2C0_SCL #6	LES_ALTEX7 #0 ACMP0_O #0 GPIO_EM4WU5

4.2 Alternate Functionality Pinout

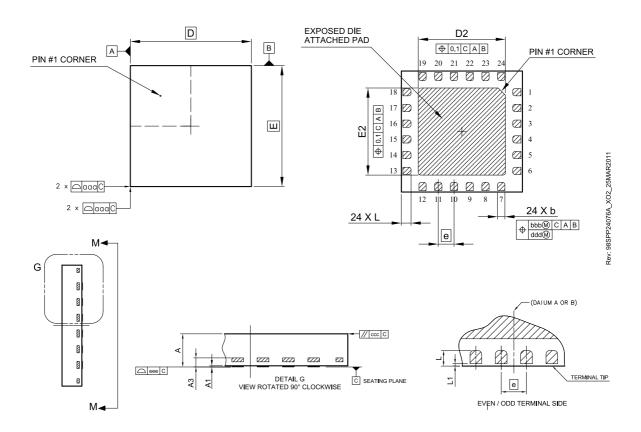
A wide selection of alternate functionality is available for multiplexing to various pins. This is shown in Table 4.2 (p. 32). The table shows the name of the alternate functionality in the first column, followed by columns showing the possible LOCATION bitfield settings.

Note



4.4 QFN24 Package

Figure 4.2. QFN24



Note:

- 1. Dimensioning & tolerancing confirm to ASME Y14.5M-1994.
- 2. All dimensions are in millimeters. Angles are in degrees.
- 3. Dimension 'b' applies to metallized terminal and is measured between 0.25 mm and 0.30 mm from the terminal tip. Dimension L1 represents terminal full back from package edge up to 0.1 mm is acceptable.
- 4. Coplanarity applies to the exposed heat slug as well as the terminal.
- 5. Radius on terminal is optional

Table 4.4. QFN24 (Dimensions in mm)

Symbol	A	A1	А3	b	D	E	D2	E2	е	L	L1	aaa	bbb	ССС	ddd	eee
Min	0.80	0.00		0.25			3.50	3.50		0.35	0.00					
Nom	0.85	-	0.203 REF		5.00 BSC		3.60	3.60	0.65 BSC	0.40		0.10	0.10	0.10	0.05	0.08
Max	0.90	0.05		0.35			3.70	3.70		0.45	0.10					

The QFN24 Package uses Nickel-Palladium-Gold preplated leadframe.

All EFM32 packages are RoHS compliant and free of Bromine (Br) and Antimony (Sb).

For additional Quality and Environmental information, please see: http://www.silabs.com/support/quality/pages/default.aspx



5 PCB Layout and Soldering

5.1 Recommended PCB Layout

Figure 5.1. QFN24 PCB Land Pattern

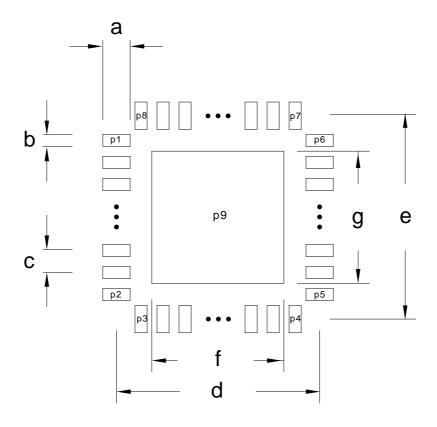


Table 5.1. QFN24 PCB Land Pattern Dimensions (Dimensions in mm)

Symbol	Dim. (mm)	Symbol	Pin number	Symbol	Pin number
а	0.80	P1	1	P8	24
b	0.30	P2	6	P9	25
С	0.65	P3	7	-	-
d	5.00	P4	12	-	-
е	5.00	P5	13	-	-
f	3.60	P6	18	-	-
g	3.60	P7	19	-	-



Figure 5.2. QFN24 PCB Solder Mask

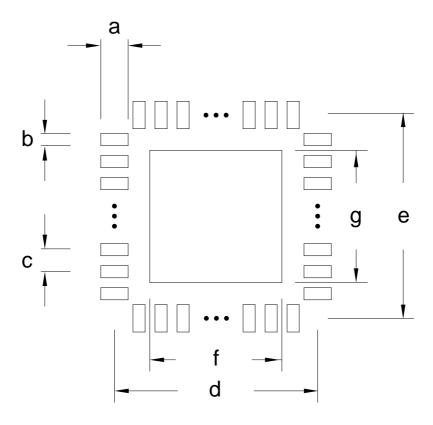


Table 5.2. QFN24 PCB Solder Mask Dimensions (Dimensions in mm)

Symbol	Dim. (mm)	Symbol	Dim. (mm)
а	0.92	е	5.00
b	0.42	f	3.72
С	0.65	g	3.72
d	5.00	-	-



Figure 5.3. QFN24 PCB Stencil Design

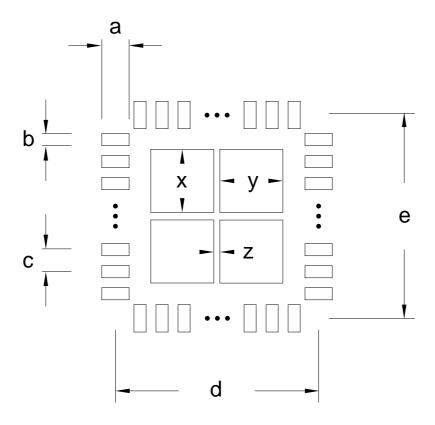


Table 5.3. QFN24 PCB Stencil Design Dimensions (Dimensions in mm)

Symbol	Dim. (mm)	Symbol	Dim. (mm)
a	0.60	е	5.00
b	0.25	Х	1.00
С	0.65	у	1.00
d	5.00	Z	0.50

- 1. The drawings are not to scale.
- 2. All dimensions are in millimeters.
- 3. All drawings are subject to change without notice.
- 4. The PCB Land Pattern drawing is in compliance with IPC-7351B.
- 5. Stencil thickness 0.125 mm.
- 6. For detailed pin-positioning, see Figure 4.2 (p. 34).

5.2 Soldering Information

The latest IPC/JEDEC J-STD-020 recommendations for Pb-Free reflow soldering should be followed.

The packages have a Moisture Sensitivity Level rating of 3, please see the latest IPC/JEDEC J-STD-033 standard for MSL description and level 3 bake conditions. Place as many and as small as possible vias underneath each of the solder patches under the ground pad.

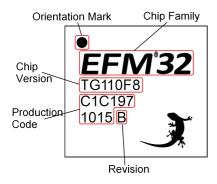


6 Chip Marking, Revision and Errata

6.1 Chip Marking

In the illustration below package fields and position are shown.

Figure 6.1. Example Chip Marking (top view)



6.2 Revision

The revision of a chip can be determined from the "Revision" field in Figure 6.1 (p. 38).

6.3 Errata

Please see the errata document for EFM32TG108 for description and resolution of device erratas. This document is available in Simplicity Studio and online at:

http://www.silabs.com/support/pages/document-library.aspx?p=MCUs--32-bit



7.4 Revision 1.20

September 30th, 2013

Added I2C characterization data.

Corrected GPIO operating voltage from 1.8 V to 1.85 V.

Document changed status from "Preliminary".

Updated Environmental information.

Updated trademark, disclaimer and contact information.

Other minor corrections.

7.5 Revision 1.10

June 28th, 2013

Updated power requirements in the Power Management section.

Removed minimum load capacitance figure and table. Added reference to application note.

Other minor corrections.

7.6 Revision 1.00

September 11th, 2012

Updated the HFRCO 1 MHz band typical value to 1.2 MHz.

Updated the HFRCO 7 MHz band typical value to 6.6 MHz.

Added GPIO_EM4WU3, GPIO_EM4WU4 and GPIO_EM4WU5 pins and removed GPIO_EM4WU1 in the Alternate functionality overview table.

Other minor corrections.

7.7 Revision 0.96

May 4th, 2012

Corrected PCB footprint figures and tables.

7.8 Revision 0.95

February 27th, 2012

Corrected operating voltage from 1.8 V to 1.85 V.

Added rising POR level and corrected Thermometer output gradient in Electrical Characteristics section.

Updated Minimum Load Capacitance (C_{I FXOI}) Requirement For Safe Crystal Startup.

Added Gain error drift and Offset error drift to ADC table.

Added reference to errata document.



7.9 Revision 0.92

July 22nd, 2011

Updated current consumption numbers from latest device characterization data.

7.10 Revision 0.91

February 4th, 2011

Corrected max DAC sampling rate.

Increased max storage temperature.

Added data for <150°C and <70°C on Flash data retention.

Changed latch-up sensitivity test description.

Added IO leakage current.

Added Flash current consumption.

Updated HFRCO data.

Updated LFRCO data.

7.11 Revision 0.90

December 1st, 2010

New peripherals added to pinout, including LESENSE and OpAmps.

7.12 Revision 0.50

May 25th, 2010

Block diagram update.

7.13 Revision 0.40

March 26th, 2010

Initial preliminary release.



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